

Standard Recovery Diodes, (Stud Version), 85 A



DO-203AB (DO-5)

PRODUCT SUMMARY			
I _{F(AV)}	85 A		

FEATURES

- High surge current capability
- · Stud cathode and stud anode version
- · Leaded version available
- Types up to 1600 V V_{RRM}
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

TYPICAL APPLICATIONS

- Battery chargers
- Converters
- · Power supplies
- · Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS					
DADAMETED	TECT COMPITIONS	85HI	LINUTO		
PARAMETER	TEST CONDITIONS	10 TO 120	140/160	UNITS	
1		8	5	Α	
I _{F(AV)}	T _C	140	110	°C	
I _{F(RMS)}		133		А	
1	50 Hz	1700 1800		۸	
I _{FSM}	60 Hz			Α	
l²t	50 Hz	14 500		A ² s	
1-1	60 Hz	13 5	500	A-5	
V _{RRM}	Range	100 to 1200	1400/1600	V	
TJ		- 65 to 180	- 65 to 150	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$\begin{aligned} & I_{RRM} \text{ MAXIMUM} \\ \text{AT T}_J &= T_J \text{ MAXIMUM} \\ & \text{mA} \end{aligned}$		
	10	100	200			
85HF(R)	20	200	300			
	40	400	500			
	60	600	700	9		
	80	800	900			
	100	1000	1100			
	120	1200	1300			
	140	1400	1500	4.5		
	160	1600	1700	4.5		

85HF(R) Series

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FORWARD CONDUCTION								
PARAMETER	SYMBOL		TECT CONDITIONS		85HF(R)		UNITS	
PARAMETER	STWIBUL	TEST CONDITIONS		10 to 120	140/160			
Maximum average forward current	I _{F(AV)}	180° conduc	ction, half sine wa	ava	8	5	Α	
at case temperature	'F(AV)	100 0011000	nion, nan sine we	1VC	140	110	°C	
Maximum RMS forward current	I _{F(RMS)}				1;	33	Α	
		t = 10 ms	No voltage		1700		- A	
Maximum peak, one-cycle forward,	leo.	t = 8.3 ms	reapplied		1800			
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1450			
		t = 8.3 ms	reapplied	Sinusoidal half wave,	15	00		
	l ² t	t = 10 ms	No voltage	_	14 500		A ² s	
Maximum I ² t for fusing		t = 8.3 ms	reapplied		13 500			
waxiinum r rior rusing		t = 10 ms	100 % V _{RRM}		10 500			
		t = 8.3 ms	reapplied		9400			
Maximum I²√t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		16	000	A²√s		
Value of threshold voltage (up to 1200 V)	V	T T		0.	68	V		
Value of threshold voltage (for 1400 V, 1600 V)	V _{F(TO)}	$T_J = T_J$ maximum			0.	69]	
Value of forward slope resistance (up to 1200 V)	_	$T_{,l} = T_{,l}$ maximum			1.	62	mΩ	
Value of forward slope resistance (for 1400 V, 1600 V)	· r _f	1.75		75	11152			
Maximum forward voltage drop	V_{FM}	$I_{pk} = 267 \text{ A}, T_J = 25 ^{\circ}\text{C}, t_p = 400 \mu \text{s rectangular wave}$ 1.2 1.4			1.4	V		

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	85H	UNITS		
PANAMETEN	STIMBUL	TEST CONDITIONS	10 to 120	140/160	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 65 to 180	- 65 to 150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0	.35	K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0	0.25		
Maximum shock (1)			15	1500		
Maximum constant vibration (1)		50 Hz	20		g	
Maximum constant acceleration (1)		Stud outwards	50	000		
		Not lubricated thread, tighting on nut (2)	3.4	(30)		
Maximum allowable mounting		Lubricated thread, tighting on nut (2)	2.3	(20)	$N \cdot m$	
torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon (3)	4.2	(37)	$(lbf \cdot in)$	
		Lubricated thread, tighting on hexagon (3)	3.2	(28)		
Approximate weight		Unleaded device	-	17	g	
Approximate weight		Onleaded device	C	0.6	oz.	
Case style		See dimensions - link at the end of datasheet	DO-	-203AB (DO-5	i)	

- (1) Available only for 88HF
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks



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∆R _{thJC} CONDUCT	△R _{thJC} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS			
180°	0.10	0.08					
120°	0.11	0.11		l			
90°	0.13	0.13	$T_J = T_J$ maximum	K/W			
60°	0.17	0.17					
30°	0.26	0.26					

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

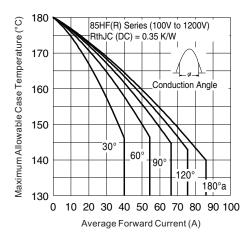


Fig. 1 - Current Ratings Characteristics

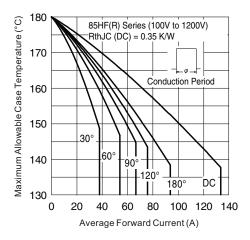


Fig. 2 - Current Ratings Characteristics

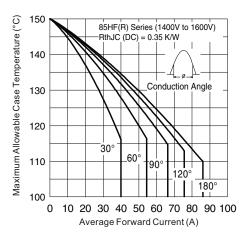


Fig. 3 - Current Ratings Characteristics

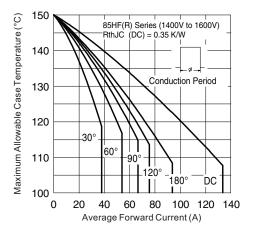


Fig. 4 - Current Ratings Characteristics

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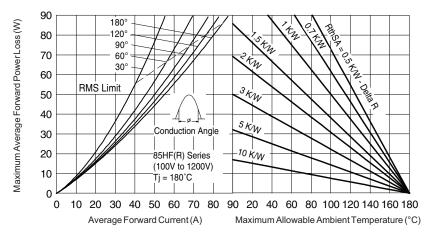


Fig. 5 - Forward Power Loss Characteristics

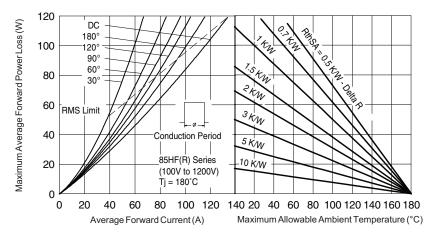


Fig. 6 - Forward Power Loss Characteristics

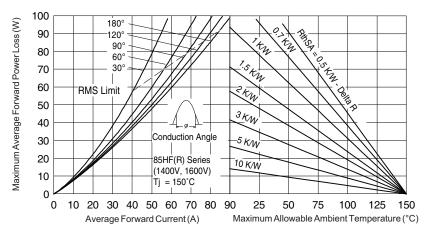


Fig. 7 - Forward Power Loss Characteristics



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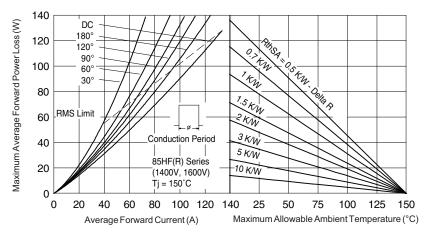


Fig. 8 - Forward Power Loss Characteristics

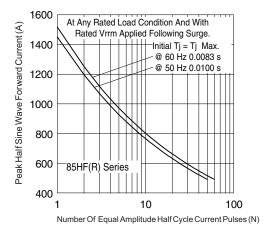


Fig. 9 - Maximum Non-Repetitive Surge Current

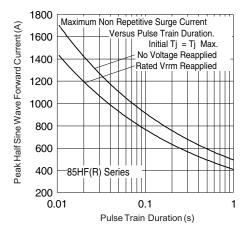


Fig. 10 - Maximum Non-Repetitive Surge Current

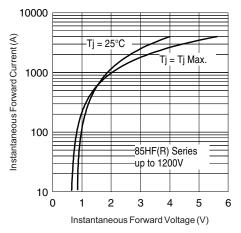


Fig. 11 - Forward Voltage Drop Characteristics (up to 1200 V)

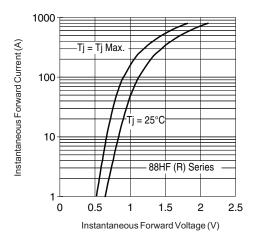


Fig. 12 - Forward Voltage Drop Characteristics (for 1400 V, 1600 V)

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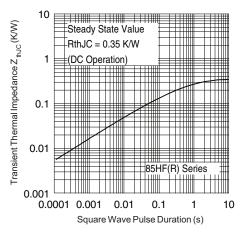
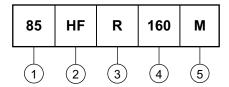


Fig. 13 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



1 - 85 = Standard device

86 = Not isolated lead

87 = Isolated lead with silicone sleeve

(red = Reverse polarity)

(blue = Normal polarity)

88 = Type for rotating application

2 - HF = Standard diode

3 - None = Stud normal polarity (cathode to stud)

R = Stud reverse polarity (anode to stud)

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

5 - None = Stud base DO-203AB (DO-5) 1/4" 28UNF-2A

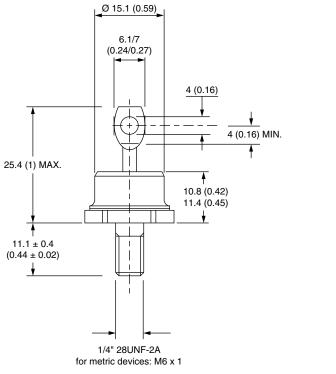
M = Stud base DO-203AB (DO-5) M6 x 1 (not available for 88HF)

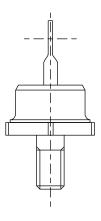
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95342		

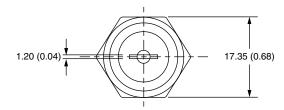


DO-203AB (DO-5) for 85HF(R) and 86HF(R) Series

DIMENSIONS FOR 85HF(R) SERIES in millimeters (inches)







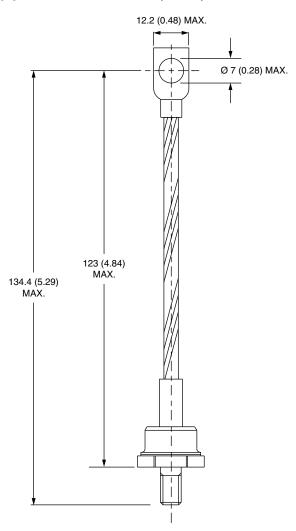
Outline Dimensions

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DO-203AB (DO-5) for 85HF(R) and 86HF(R) Series



DIMENSIONS FOR 86HF(R) SERIES in millimeters (inches)





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